

# 深圳市强生光电科技有限公司

Shenzhen JNJ Optoelectronics Co.,Limited

## 产品规格书

SPECIFICATION FOR APPROVAL

|                    |                               |
|--------------------|-------------------------------|
| 客户名称<br>Customer   |                               |
| 产品型号<br>Part No    | JNJ-S-2016PB-940005-PT3-BD-D1 |
| 产品料号<br>Product No | 30100552                      |
| 版本<br>Revision     | A/1                           |
| 制作日期<br>Date       | 2024-05-17                    |

|                                                                                     |                                                                                     |                                                                                     |                                                                                       |
|-------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
| 制作<br>Producer                                                                      | 工程部<br>Engineering Dept.                                                            | 业务部<br>Business department                                                          | 批准<br>Approval                                                                        |
|  |  |  |  |

| 客户承认结果<br>Customer acknowledges Results |  |  |
|-----------------------------------------|--|--|
|                                         |  |  |

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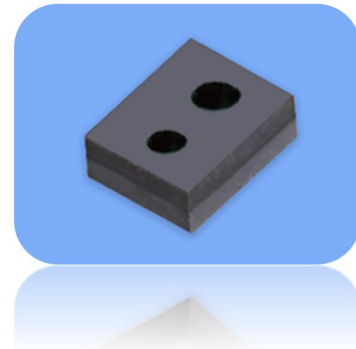
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## 产品构造 Product conformation:

- 封装胶水: 黑色硅胶  
Packaging glue: Black silicone
- 发光颜色: 红外(不可见光) 波长 940nm+PT 芯片  
Luminous color: Infrared (invisible light) wavelength 940nm
- 芯片规格: 红外 Vcsel 6mil\*6mi+PT 16mil\*16mil  
Chip specification: IR Vcsel 6mil\*6mil+PT 16mil\*16mil
- 静电敏感材质  
Electrostatic sensitive material

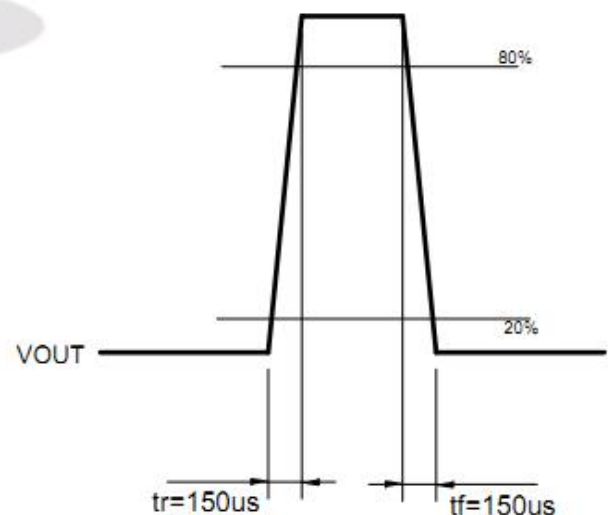
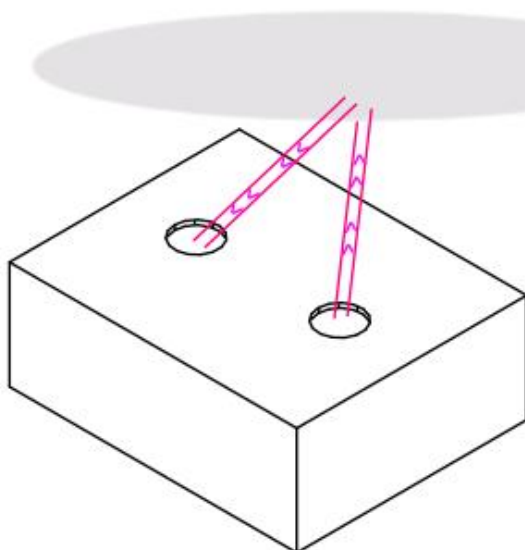


## 应用 Applications:

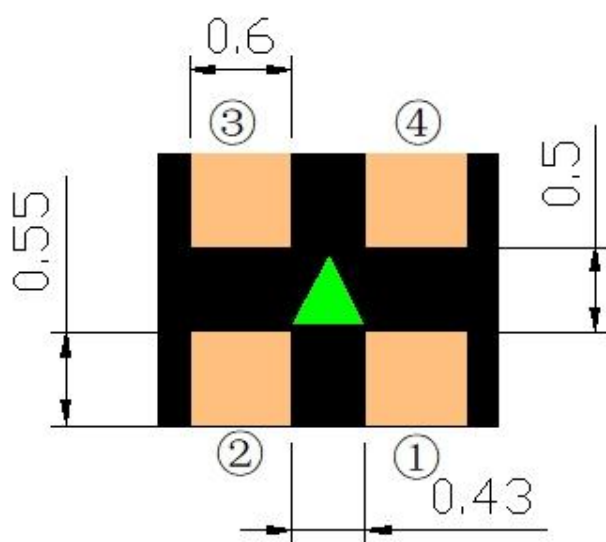
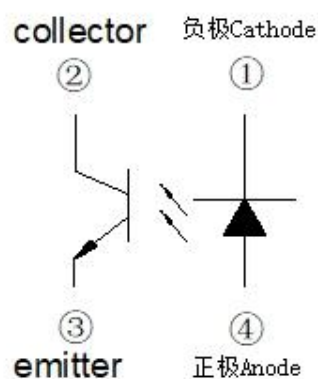
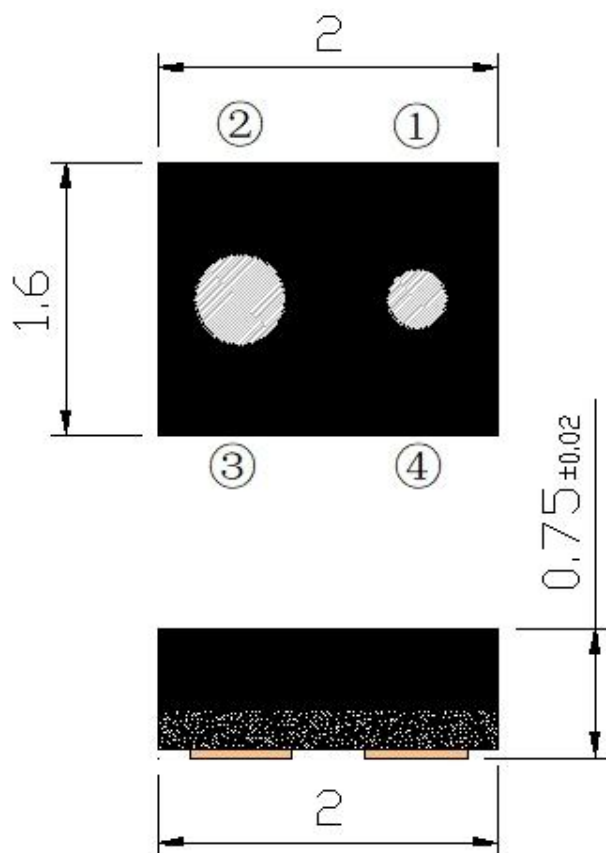
- 入耳式耳机 in-ear monitor
- 智能穿戴 Smart wear

工作流程: 用IO口控制传感器的红外发光部份工作时另一个IO口同时测量传感器的VOUT脚位上是否有高电平? 接收到反射信号后VOUT脚输出对应的线性电压, 信号越强电压越高。应用电路图实测80%输出入耳检测距离>2mm。

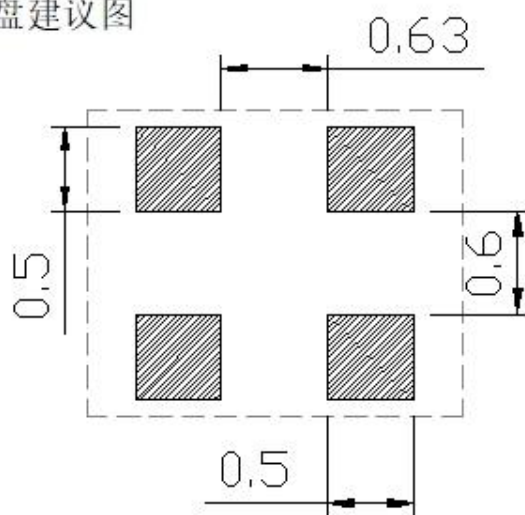
例如采用250us工作50ms休息(平均电流在30uA): 待机电流180nA



**产品外形尺寸 Package outline dimensions:**



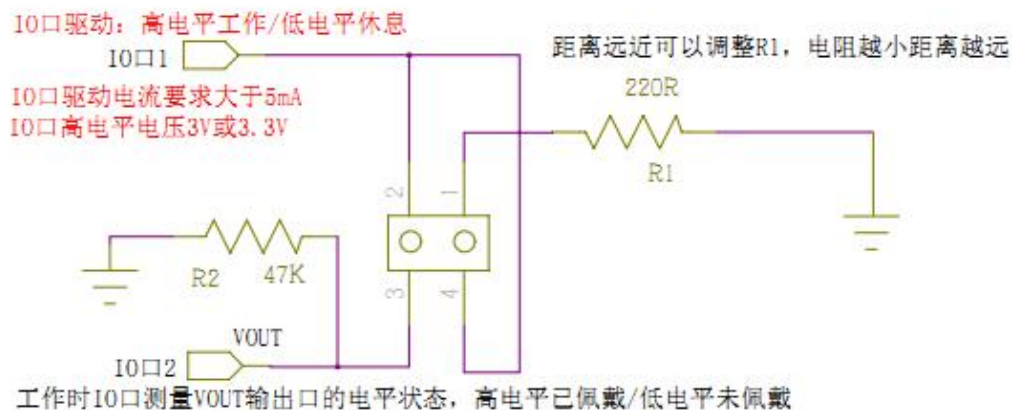
焊盘建议图



**备注(Note):**

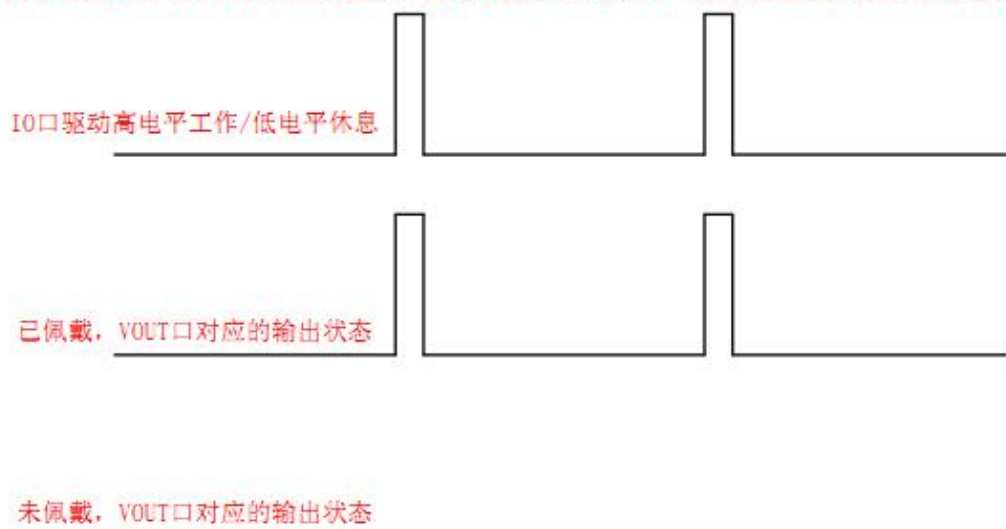
1. 标注尺寸单位为毫米  
Dimensions are in millimeters.
2. 除特别标注外, 所有尺寸允许公差 $\pm 0.1\text{mm}$ .  
Tolerances unless mentioned are  $\pm 0.1\text{mm}$ .

## 典型应用电路



## 应用电路时序

例如采用250us工作50ms休息（平均电流在30uA），时序根据实际应用调整。待机电流180nA

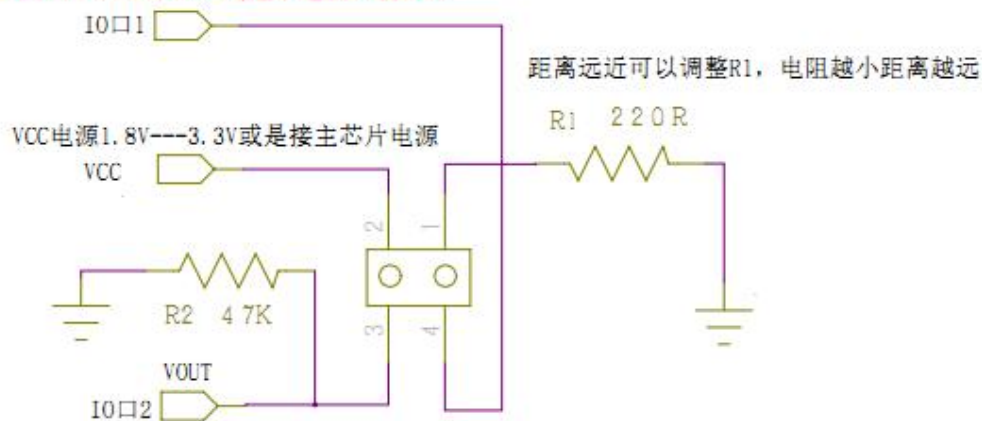


| 工作状态 | 驱动口<br>10口1 | 检测口<br>10口2 | 结果  |
|------|-------------|-------------|-----|
| 工作中  | 1           | 1           | 已佩戴 |
|      | 1           | 0           | 未佩戴 |
| 休眠中  | 0           | 0           |     |

## 抗太阳光误动作应用电路 3VIO口驱动

IO口驱动：高电平工作/低电平休息

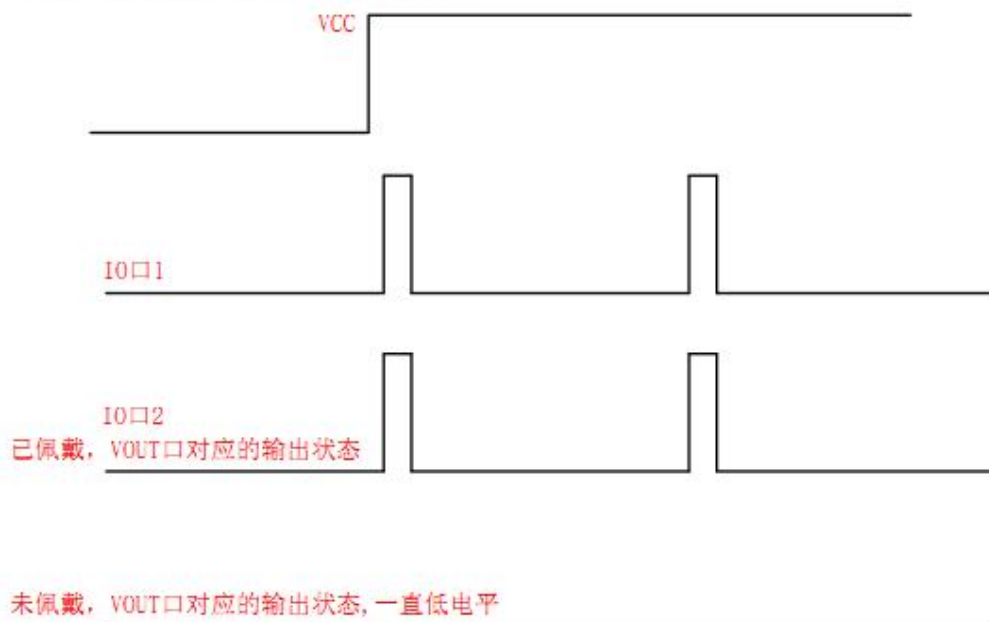
IO口驱动电流要求大于5mA IO口高电平电压3V或3.3V



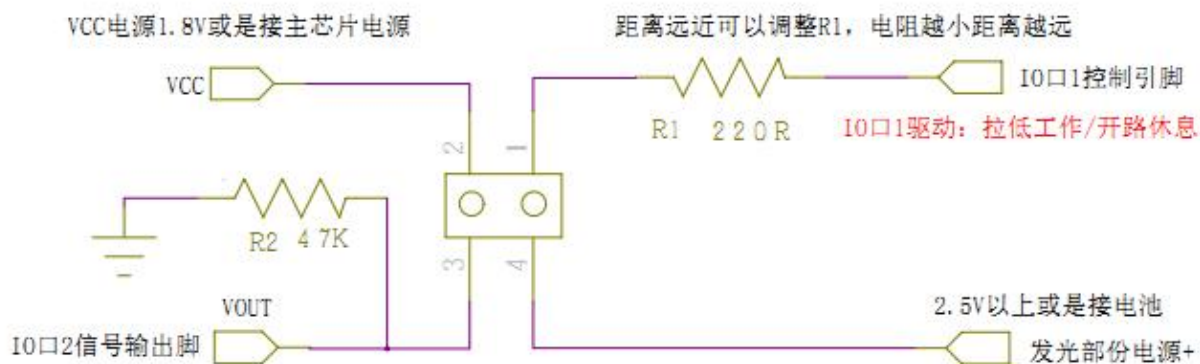
## 应用电路工作时序

例如采用250us工作50ms休息（平均电流在30uA），时序根据实际应用调整。待机电流180nA

IO口1为驱动高电平工作/低电平休息

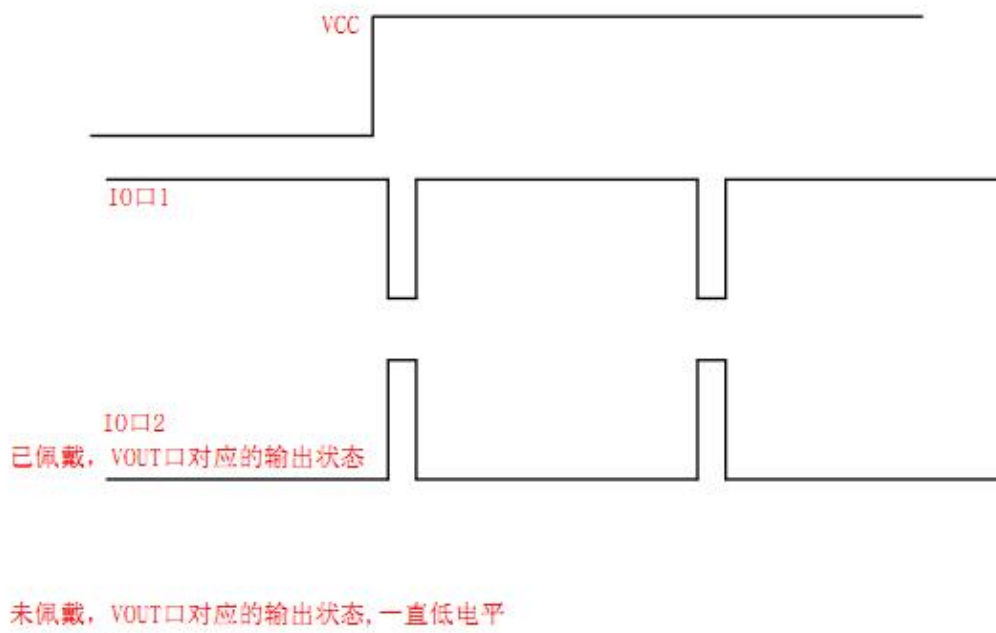


## 抗阳光误动作应用电路 1.8VIO 口驱动



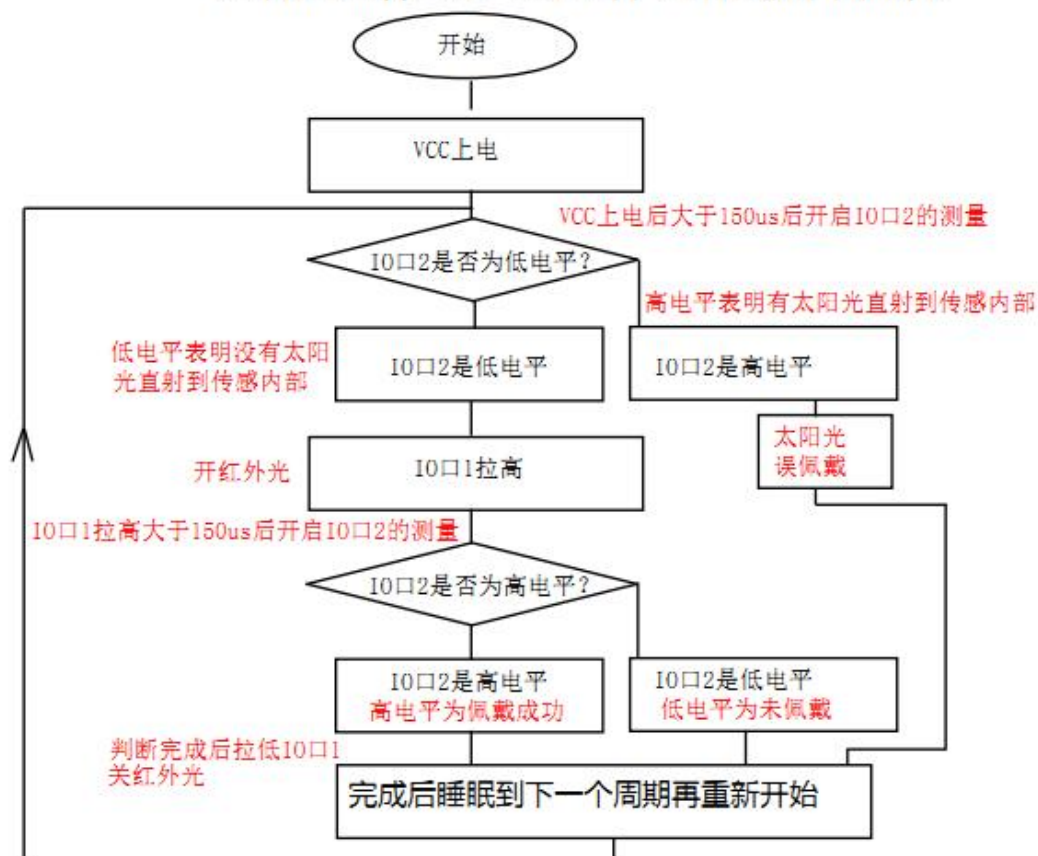
## 应用电路工作时序

例如采用250us工作50ms休息（平均电流在30uA），时序根据实际应用调整。待机电流180nA





## 应用电路250 us工作内的软件流程



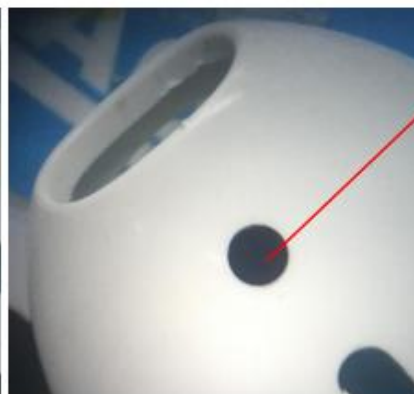
## 结构安装

传感器要紧贴到滤光片的定位区域中，滤光片过滤800nm以下的波长。

传感器安装位置



滤光片厚度  
0.5mm



**极限参数 Absolute Maximum Rating sat:**

| 参数<br>Parameter                    | 符号<br>Symbol | 额定值<br>Rated Value | 单位<br>Unit | 环境温度<br>condition Temperature |
|------------------------------------|--------------|--------------------|------------|-------------------------------|
| 最大脉冲工作电流*Max Pulse Current         | IFP          | 7                  | mA         | Ta=25°C                       |
| 反向电压 Reverse Voltage               | VR           | 5                  | V          | Ta=25°C                       |
| 工作温度 Operating Temperature         | Topr         | -30°C to +80°C     | °C         |                               |
| 存储温度 Storage Temperature           | Tstg         | -40°C to +85°C     | °C         |                               |
| 回流焊温度 Reflow Soldering Temperature | Tsol         | 245°C for 10sec    | °C         |                               |
| 结温 Junction Temperature            | Tj           | 115                | °C         |                               |

\*Pulse condition : pulse width (tp) =100us, duty cycle=10%

**光性能特点 Optical Characteristics:**

| 芯片<br>Chip                            | 参数<br>Parameter                  | 符号<br>Symbol      | 测试条件<br>test condition                      | 最小<br>Min | 典型<br>Typ | 最大<br>Max | 单位<br>Unit |
|---------------------------------------|----------------------------------|-------------------|---------------------------------------------|-----------|-----------|-----------|------------|
| VcseI                                 | 阈值电流 Threshold Current           | Ith               | T <sub>C</sub> =25°C                        | ---       | 0.9       | 1.2       | mA         |
|                                       | 光功率 Output Power                 | Lop               | IF=7mA                                      | 5         | 6         | ---       | mW         |
|                                       | 正向电压 Forward Voltage             | VF                | IF=7mA                                      | ---       | 1.9       | 2.2       | V          |
|                                       | 波长 Wavelength                    | λp                | IF=7mA                                      | ---       | 940       | ---       | nm         |
|                                       | 斜率效率 Slop Efficiency             | SE                | T <sub>C</sub> =25°C                        | 0.9       | 1.0       | ---       | W/A        |
|                                       | 转换效率 Power Conversion Efficiency | PCE               | IF=7mA                                      | 40        | 42        | ---       | %          |
|                                       | 发散角 Divergence Angle(1/e2)       | 2θ1/2             | IF=7mA                                      | ---       | 21        | ---       | Deg        |
| PT                                    | 集电极-发射极反向击穿电压                    | BV <sub>CEO</sub> | I <sub>C</sub> =100μA; I <sub>B</sub> =0    | 90        | 120       | 160       | V          |
|                                       | 发射极-基极反向击穿电压                     | BV <sub>EBO</sub> | I <sub>E</sub> =100μA; I <sub>C</sub> =0    | 7         | 9         | 11        | V          |
|                                       | 集电极暗电流                           | I <sub>CEO</sub>  | V <sub>CE</sub> =50V; H=0mW/cm <sup>2</sup> | ---       | 10        | 60        | nA         |
|                                       | 集电极-基极反向击穿电压                     | BV <sub>CBO</sub> | I <sub>B</sub> =10uA; I <sub>E</sub> =0     | 100       | ---       | 350       | V          |
|                                       | 集电极-发射极饱和压降                      | V <sub>CES</sub>  | I <sub>C</sub> =2mA; I <sub>B</sub> =100μA  | ---       | ---       | 0.2       | V          |
|                                       | 电流增益                             | h <sub>FE</sub>   | V <sub>CE</sub> =5V; I <sub>C</sub> =2mA    | 500       | ---       | 2500      | ---        |
| 抗静电 Electrostatic Discharge Threshold |                                  | ESD               | Human Body Model                            | ---       | ---       | 2000      | V          |

备注(Note):

- 上述辐射通量的测试允许公差是±10% , 电压测量误差±0.1v, 波长测量误差±1nm  
The test of the above radiation flux allows a tolerance of ± 10%, voltage measurement error of ± 0.1v, and wavelength measurement error of ± 1nm
- 使用时请用恒流驱动, 恒压驱动时电流会偏差较大。  
Please use constant current drive, and the current deviation of constant voltage drive will be large.



**信赖性测试项目及条件 Reliability Test:**

| 测试项目<br>Test Parameter                                   | 参考标准<br>Reference Criterion | 试验条件<br>Test Condition                      | 数量<br>Quantity | 接受/拒收<br>Ac/Re |
|----------------------------------------------------------|-----------------------------|---------------------------------------------|----------------|----------------|
| 回焊耐热性<br>Soldering resistance test                       | JESD22-B106                 | Ta=245℃, T=10±1sec, 3 times Reflow          | 30Pcs          | 0/1            |
| 冷热冲击保存试验<br>Thermal shock storage test                   | JESD22-A106                 | Ta=-40℃~+100℃,<br>T=(30min~30min)×100Cycles | 20Pcs          | 0/1            |
| 高温保存试验<br>High temperature storage test                  | JESD22-A103                 | Ta=100℃, T=1000HR                           | 20Pcs          | 0/1            |
| 低温保存试验<br>Low temperature storage test                   | JESD22-A119                 | Ta=-40℃, T=1000HR                           | 20Pcs          | 0/1            |
| 常温通电试验<br>Continuous operating test                      | JESD22-A108                 | IF=*mA, Ta=25℃, T=1000HR                    | 30Pcs          | 0/1            |
| 高温高湿通电试验<br>High temperature and humidity operating test | JESD22-A101                 | IF=*mA, Ta=85℃, RH=85%RH, T=1000HR          | 20Pcs          | 0/1            |

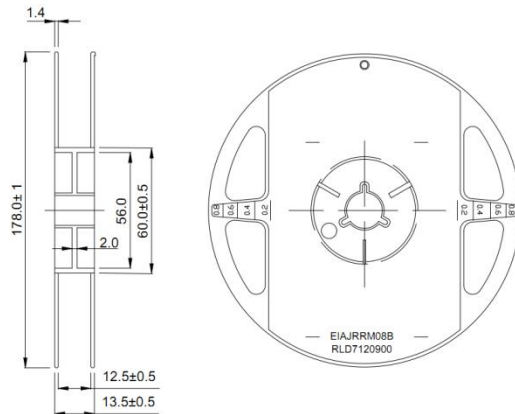
**失效判定标准 Judgement standard fail**

| 项目<br>Parameter         | 符号<br>Symbol | 测试条件<br>Test Condition | 判定标准<br>Judgement standard |          |
|-------------------------|--------------|------------------------|----------------------------|----------|
|                         |              |                        | 最小 Min                     | 最大 Max   |
| 正向电压<br>Forward Voltage | VF(V)        | IF=*mA                 | --                         | USL*×1.2 |
| 反向电流<br>Reverse current | IR(μA)       | VR=*V                  | --                         | USL*×2.0 |
| 输出功率<br>Output Power    | Lop(mW)      | IF=*mA                 | Initial value×0.7          | --       |

**备注(Note):**

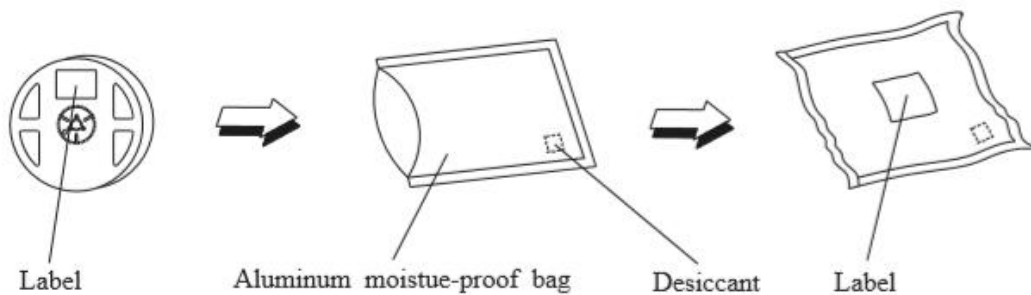
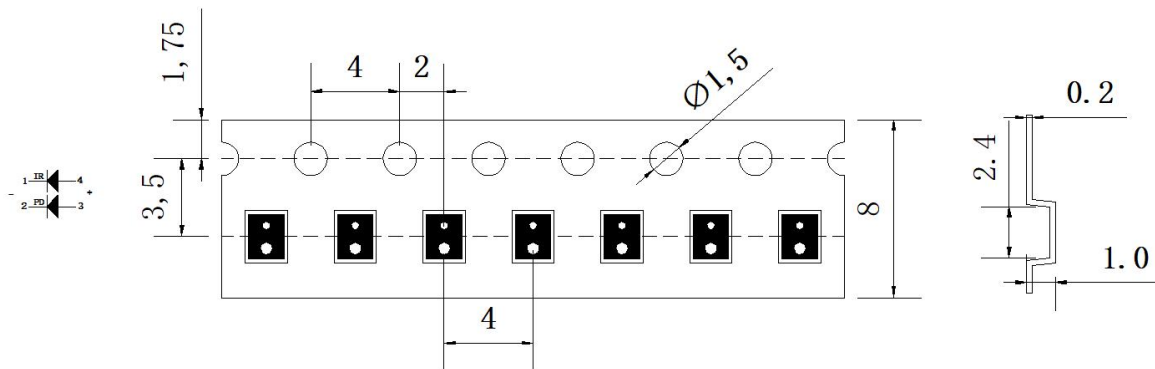
- USL: 规格上限; LSL 规格下限
- 数据表格中所示的技术信息仅限于典型特征值和电路实例引用的产品, 它既不构成工业特性的保证, 也不构成任何许可的授权  
The technical information shown in the data table is limited to products referenced by typical eigenvalues and circuit instances and does not constitute a guarantee of industrial characteristics nor does it constitute an authorization of any license
- \*mA: 试验电流;  
\*mA: test current;

**卷轴尺寸 Reel Dimensions:**



**使用方向及尺寸 Progressive direction and Dimensions:**

**Loaded quantity 4000PCS per reel**



**标签规格 Label Form Specification:**

|          |                |               |
|----------|----------------|---------------|
| 产品名称:    | XXXXXXXXXXXXXX |               |
| 批次号:     | XXXXXXXX       |               |
| 规格型号:    | XXXXXXXX       | XXXXXXXX      |
| 色温/波段:   | XXXX K-XXXX K  | XXX NM-XXX NM |
| 电压(5mA): | XXX V-XXX V    | XXX V-XXX V   |
| 色 区:     | XXX            | /             |
| 数 量:     | XXXX PCS       |               |
| 日 期:     | XXXX-XX-XX     |               |

注: 开封后请于24小时内完成使用

**LED 应用注意事项 Application precautions:****保存及使用 Preservation and use:**

1. 在打开包装前, LED 应存放在 30℃/60%RH 或以下的环境中。打开包装后, LED 应置于 20-30℃/30%RH 或以下的环境中使用。  
Before opening the package, the LED should be stored at 30℃/60%RH or less. After opening the package, the LED should be placed in an environment of 20-30℃/30%RH or less.
2. molding 封装及 SMD LED 开封后要在 24H 之内使用, 为了避免环境的影响, 建议拆封后, 经过 60℃/24H 除湿, 没用完 LED 需及时做抽真空包装处理, 避免再次使用时发生失效。  
To avoid the impact of the environment, it is recommended to dehumidify after unpacking at 60℃/24H. All the leds are needed to be vacuumed to avoid failure
3. 若干燥剂褪色或过期使用, 需干燥烘烤: 60±5℃/24 小时。  
If the desiccant faded or expired use, dry baking: 60±5℃/24 hours.
4. LED 的胶表面易沾灰尘, 需要做好相关防尘措施。  
LED Glue surface easy to dust, need to do the relevant dust prevention measures.

**取放 pick and place**

夹取 LED 时只能触及支架体, 镊子之类的工具不要对透镜施压。更不要刺或推透镜。

When taking the LED, you should only touch the bracket. Tools such as tweezers should not put pressure on the lens. Don't stab or push the lens.

**热量处理 Heat treatment**

在过大电流驱动时 LED 的  $T_j$  (节点温度) 会超过期限限制值, 这导致 LED 的寿命严重缩短, 热量处理措施要有效的减小应用产品的热阻。比较通用的做法: 把 LED 封装器件安装在金属基质的 PCB 板上。1W LED 产品要求金属基板的表面散热面积至少 30cm<sup>2</sup> (3W 产品建议 80cm<sup>2</sup> 以上), 且其导热系数要高于 2.0W/mK。LED 和金属基板结合靠导热性较好的导热胶, 要求导热系数高于 1.0W/mK, 厚度小于 100um。

When driven by excessive current, the  $T_j$  (node temperature) of LED will exceed the period limit value, which leads to a serious shortening of LED life. Thermal treatment measures should effectively reduce the thermal resistance of application products. Common practice: install LED packages on metal matrix PCB boards. 1W LED products require the surface heat dissipation area of the metal substrate to be at least 30cm squared (over 80cm squared is recommended for 3W products), and its thermal conductivity is higher than 2.0w /mK. LED and gold substrate are combined by thermal conductive adhesive with good thermal conductivity. The thermal conductivity coefficient is required to be higher than 1.0w /mK and the thickness is less than 100um.

**清洁 Clean**

需要清洁的话, 用干净的软碎布沾点酒精轻力擦除异物, 不可以采用诸如丙酮之类的清洁剂以免可能造成腐蚀破坏。

If you need to clean, use a clean, soft cloth dipped in alcohol to gently remove foreign matter. Do not use a cleaner such as acetone to avoid possible corrosion damage.

**电性注意事项 Electrical precautions**

1. LED 不允许反向驱动。  
Led Reverse drive is not allowed
2. 限流措施是必要的, 否则轻微的电压变化会导致较大的电流变化, 可能造成 LED 失效。  
Current limiting measures are necessary, otherwise slight voltage changes will lead to large current changes, which may lead to LED failure.
3. 在发光量满足要求的前提下, 推荐采用低于额定电流的驱动电流, 这样有利于提高产品的可靠性。  
Under the premise that the luminous quantity meets the requirements, it is recommended to use the drive current lower than the rated current, which is conducive to improving the reliability of the product.

**防静电措施 anti-static precautions**

LED 是静电敏感器件, 在保存、使用过程中要采取防静电措施。静电和电涌会导致产品特性发生改变, 例如正向电压降低等, 情况严重甚至会损毁产品。所以对于整个工序 (生产, 测试, 包装等) 与 LED 直接接触的员工都要做好防止和消除静电的措施。所有相关的设备和机器都应该正确接地。接地交流电阻小于 1.0 欧姆, 工作台上需垫表面电阻 106-109 欧姆的桌垫。在容易产生静电的环境和设备上, 还必须安装离子风扇。作业过程中, 操作员需使用防静电手环, 防静电垫子, 防静电工作服, 工作鞋, 手套, 防静电电容等。

LED is electrostatic sensitive devices, in the process of preservation, use to take anti-static measures. Static electricity and surge can lead to changes in product characteristics, such as forward voltage reduction, which can be serious and even damage the product. So for the whole

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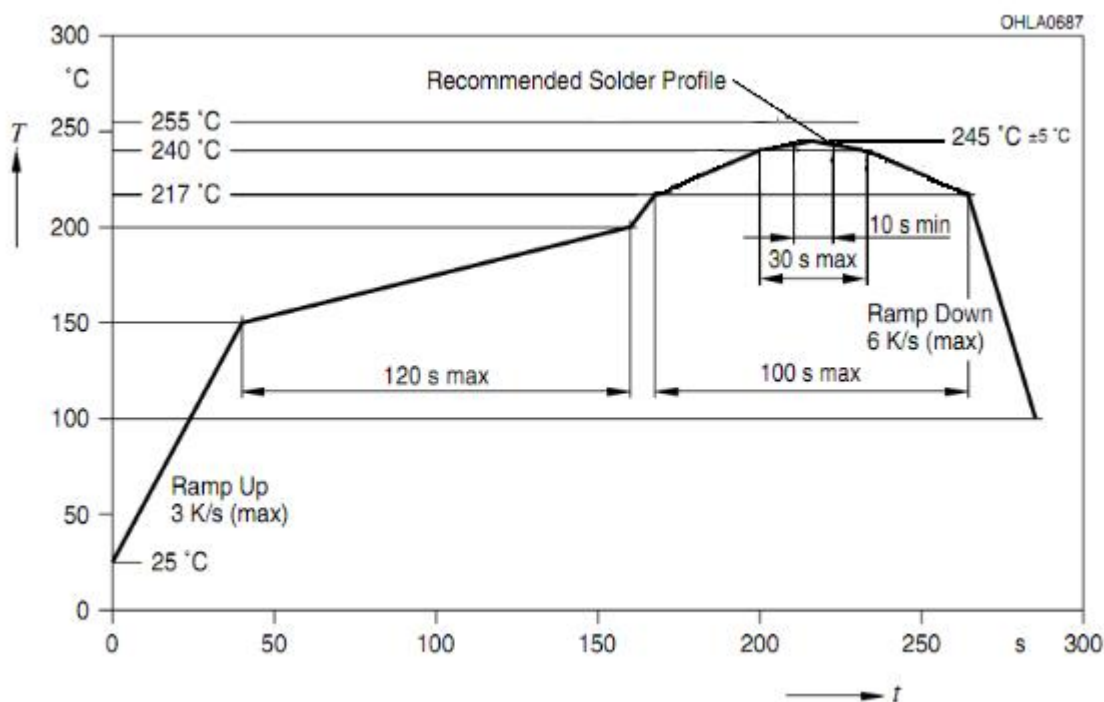
process (production, testing, packaging, etc.) and LED direct contact staff should do a good job to prevent and eliminate electrostatic measures. All related equipment and machinery should be properly grounded. The grounding ac resistance is less than 1.0 ohm, the table mat with surface resistance of 106-109 ohm is needed on the work table. Ion fans must also be installed in electrostatic environments and equipment. During the operation, the operator should use anti-static bracelet, anti-static mat, anti-static overalls, working shoes, gloves, anti-static capacity.

### 电烙铁焊接 An electric soldering iron

建议使用防静电电烙铁，尖端处温度不超过 350℃，每次焊锡时少于 3 秒。电烙铁的功率宜低于 60W。每焊完一次之后间隔 2 秒以上，分别焊好两个电极引脚。焊接时不可对透镜用力施压。LED 如有问题一般都是从焊锡时开始出现。故必须按要求小心作业。

It is recommended to use anti-static electric soldering iron, the temperature at the tip does not exceed 350℃, less than 3 seconds for each soldering. The power of the soldering iron should be less than 60W. Weld two electrode pins more than 2 seconds after each welding. Do not force the lens during welding. Problems with leds usually begin when they are soldered. So you must work carefully as required.

### SMT 回流焊说明 Reflow instructions:



### 注意事项 matters need attention:

1. 回流焊只允许做一次。  
Reflow soldering is only allowed once.
2. 回流焊过程中不要对灯体施加压力。  
Do not apply pressure to the lamp body during reflow
3. 回流焊完成之后不要挤压散热板、不可压到胶体部分。  
After reflow welding is completed, do not press the heat dissipation plate, do not press to the colloidal part.
4. 若有比较低熔点的锡膏，TP 可以适当降低。  
If there is a lower melting point of solder paste, TP can be appropriately reduced.